SPICE Device Model SiR688DP



Vishay Siliconix

N-Channel 60 V (D-S) MOSFET

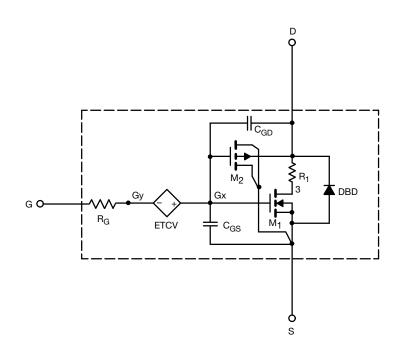
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge



SUBCIRCUIT MODEL SCHEMATIC

Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

S13-2643-Rev. A, 30-Dec-13





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SPECIFICATIONS ($T_J = 25 \text{ °C}$, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.2	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.0028	0.0029	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$	0.0045	0.0043	
Forward Transconductance ^a	g fs	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	90	70	S
Diode Forward Voltage	V _{SD}	I _S = 10 A	0.76	0.74	V
Dynamic ^b					
Input Capacitance	C _{iss}	V_{DS} = 30 V, V_{GS} = 0 V, f = 1 MHz	3120	3105	pF
Output Capacitance	C _{oss}		1210	1240	
Reverse Transfer Capacitance	C _{rss}		98	95	
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	41	44	nC
			20	20.5	
Gate-Source Charge	Q _{gs}	V_{DS} = 30 V, V_{GS} = 4.5 V, I_D = 20 A	8.6	8.6	
Gate-Drain Charge	Q _{gd}		4.7	4.7	

Notes

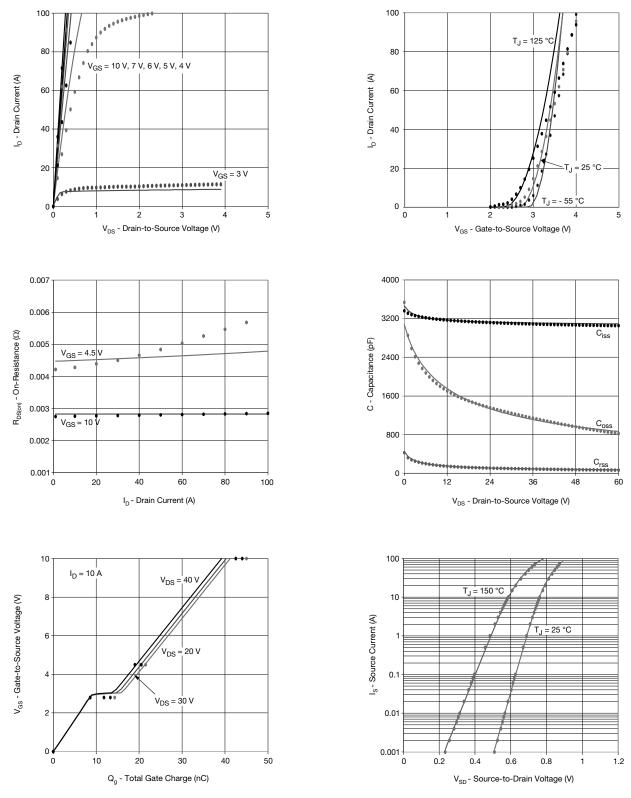
a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

· Dots and squares represent measured data.

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Document Number: 63237



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